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# National Semiconductor

# 54LVX3384 10-Bit Low Power Bus Switch

## **General Description**

The 54LVX3384 provides 10 bits of high-speed CMOS TTL-compatible bus switches. The low on resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise. The device is organized as two 5-bit switches with separate bus enable ( $\overline{OE}$ ) signals. When  $\overline{OE}$  is low, the switch is on and port A is connected to port B. When  $\overline{OE}$  is high, the switch is open and a high-impedance state exists between the two ports.

### Features

- $4\Omega$  switch connection between two ports
- Minimal propagation delay through the switch
- Ultra low power with <0.1 µA typical I<sub>CC</sub>
- Zero ground bounce in flow-through mode
- Control inputs compatible with TTL levels
- Available in CDIP and Cerpack Packaging

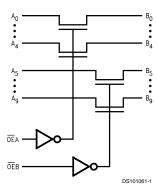
**Connection Diagram** 

Standard Microcircuit Drawing (SMD) 5962-9950701

## **Ordering Code**

Order Number	Package Number	Package Description
54LVX3384J-QML	J24F	24-Lead Ceramic Dual-in-line
54LVX3384W-QML	W24C	24-Lead Cerpack

# Logic Diagram



# Pin Descriptions

Pin Names	Description
OEA, OEB	Bus Switch Enable
A <sub>0</sub> -A <sub>9</sub>	Bus A
B <sub>0</sub> -B <sub>9</sub>	Bus B

#### Pin Assignment for CDIP and Cerpack ŌĒA 24 V<sub>CC</sub> 23 B<sub>9</sub> Bo A 22 Ac A<sub>1</sub> A۹ B B<sub>8</sub> B · B-, A-A 1.7 A۴ B-16 • B<sub>6</sub> Β, 10 • B<sub>5</sub> A 14 - A5 GND - OEB 13 DS101061-2

# **Truth Table**

OEA	OEB	$B_0 - B_4$	B <sub>5</sub> –B <sub>9</sub>	Function
L	L	A <sub>0</sub> -A <sub>4</sub>	A <sub>5</sub> -A <sub>9</sub>	Connect
L	н	A <sub>0</sub> -A <sub>4</sub>	HIGH-Z State	Connect
Н	L	HIGH-Z State	A <sub>5</sub> -A <sub>9</sub>	Connect
Н	Н	HIGH-Z State	HIGH-Z State	Disconnect

## Absolute Maximum Ratings (Note 1)

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If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V <sub>CC</sub> )	-0.5V to +7.0V
DC Switch Voltage (V <sub>S</sub> )	-0.5V to +7.0V
DC Input Voltage (V <sub>IN</sub> ) (Note 2)	-0.5V to +7.0V
DC Input Diode Current (I <sub>IK</sub> ) V <sub>IN</sub> <0V	–20 mA
DC Output (I <sub>OUT</sub> ) Sink Current	100 mA
Storage Temperature Range (T <sub>STG</sub> )	–65°C to +150°C
Power Dissapation	500mW
Junction Temperature (T <sub>J</sub> )	175°C

**DC Electrical Characteristics** 

# Recommended Operating Conditions (Note 3)

4.5V to 5.5V
0V to 5.5V
0nS/V to 5nS/V
0nS/V to DC

Note 2: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Note 3: Unused control inputs must be held HIGH or LOW. They may not float.

Symbol	Parameter	V <sub>cc</sub> (V)	T <sub>A</sub> = −55°C to +125°C		Units	Condition
			Min	Max		
VIC	Clamp Diode Voltage	4.5		-1.2	V	I <sub>IN</sub> = – 18mA
VIH	High Level Input Voltage	4.5-5.5	2.0		V	
VIL	Low Level Input Voltage	4.5-5.5		0.8	V	
Ц	Input Leakage Current	5.5		±1.0	μA	$0 \le V_{IN} \le 5.5V$
l <sub>oz</sub>	TRI-STATE Leakage Current	5.5		±10.0	μA	$0 \le A, B \le V_{CC}$
R <sub>ON</sub>	Switch On Resistance	4.5		10	Ω	V <sub>IN</sub> = 0V, I <sub>IN</sub> = 30mA
	(Note 4)	4.5		20	Ω	V <sub>IN</sub> = 0V, I <sub>IN</sub> = 15mA
I <sub>cc</sub>	Quiescent Supply Current	5.5		10	μA	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$
$\Delta I_{CC}$	Increase in I <sub>cc</sub> per Input	5.5		2.5	mA	One input at 3.4V
						Other inputs at V <sub>CC</sub> or GND
IOFF	Power Off Leakage Current	0.0		10	μA	V <sub>IN</sub> = 5.5V or 0.0V
los	Short Circuit Output Current	4.5	80		mA	$V_{IN} = 4.5V, V_{OUT} = 0.0V$
	(Note 5)					

Note 4: Measured by voltage drop between A and B pin at indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

Note 5: Not more than one output tested at a time.

Symbol	Parameter	$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$ $C_L = 50 \text{ pF},$ $RU=RD=500\Omega$ $V_{CC} = 4.5 - 5.5V$		Units	Conditions	Figure No.
		Min	Max			
t <sub>PHL</sub> , t <sub>PLH</sub>	Prop Delay Bus to Bus (Note 6)		0.25	ns	V <sub>I</sub> = open	Figures 1, 2
t <sub>PZH</sub> , t <sub>PZL</sub>	Output Enable Time $\overline{OE}_{\mathbb{A}}, \overline{OE}_{\mathbb{B}}$ to An, Bn	1.0	6.0	ns	$V_{I} = 7V$ for $t_{PZL}$ $V_{I} = open$ for $t_{PZH}$	Figures 1, 2
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Output Disable Time $\overline{OE}_A, \overline{OE}_B$ to An, Bn	1.0	6.0	ns	$I_1 = 7V$ for $t_{PLZ}$ $V_1 = open for t_{PHZ}$	Figures 1, 2

Note 6: This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the typical On resistance of the switch and the 50pF load capacitance, when driven by an ideal voltage the source (zero output impedance).

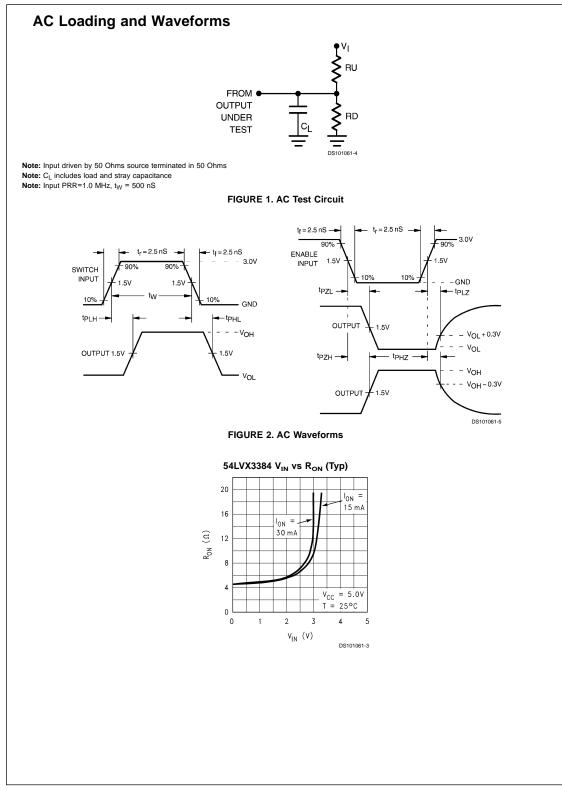
# Capacitance (Note 7)

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Symbol	Parameter	Max	Units	Conditions
CIN	Control Input Capacitance	10	pF	V <sub>CC</sub> = Open
C <sub>I/O</sub> (OFF)	Input/Output Capacitance	12	pF	$V_{CC}, \overline{OE} = 5.0V$

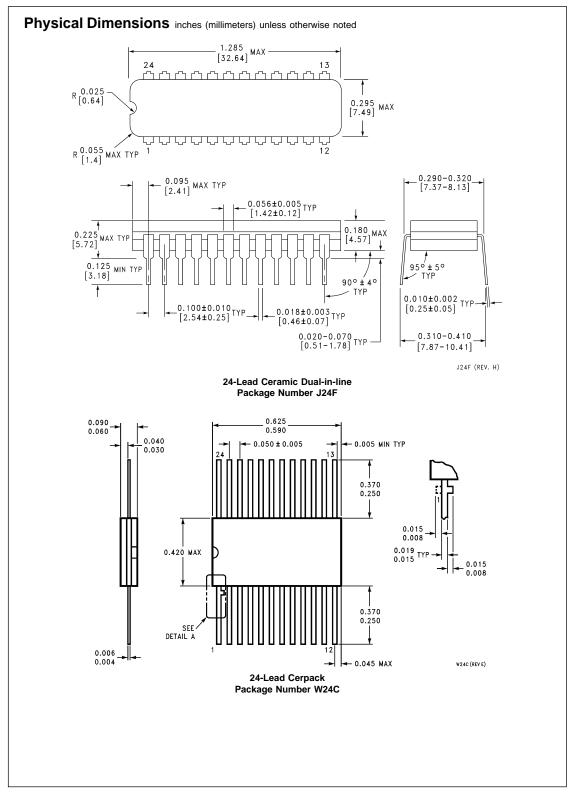
Note 7: Capacitance is characterized but not tested.

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